

## The oxidation states of titanium and niobium in compounds of composition $Sn_xNbTiP_3O_{12}$ (0 < x $\leq$ 0.50): an XPS study

José F. Marco,<sup>a\*</sup> J. Ramón Gancedo<sup>a</sup> and Frank J. Berry<sup>b\*</sup>

<sup>a</sup> Instituto de Química-Física "Rocasolano", CSIC, C/ Serrano 119, 28006 Madrid, Spain

<sup>b</sup> Department of Chemistry, The Open University, Walton Hall, Milton Keynes MK7 6AA, U.K.

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Abstract—The oxidation states of titanium and niobium in compounds of composition  $Sn_xNbTiP_3O_{12}$ (0 < x  $\leq$  0.50) have been examined by X-ray photoelectron spectroscopy. The incorporation of tin as  $Sn^{2+}$  within the NbTiP<sub>3</sub>O<sub>12</sub> structure results in the partial reduction of Ti<sup>4+</sup> to Ti<sup>3+</sup> and of Nb<sup>5+</sup> to Nb<sup>4+</sup>. The Ti 2p and Nb 3d core levels are characterized by high binding energies, suggesting highly ionic character in the Ti—O and Nb—O bonds. © 1997 Elsevier Science Ltd

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Compounds of composition  $A^{I}M_{2}^{IV}P_{3}O_{12}$  have structures which involve the corner sharing of PO<sub>4</sub> tetrahedra with MO<sub>6</sub> octahedra, thereby producing a three-dimensional linked channel network in which the A ions can be located [1-4]. The A ions can occupy two different sites within the channels [3]. The type I sites have a distorted octahedral coordination and are situated between two  $MO_6$  octahedra along the c axis to produce ribbons of O<sub>3</sub>MO<sub>3</sub>AO<sub>3</sub>MO<sub>3</sub>. The type II sites are larger with 8-10 coordinating oxygen ions and are located between the ribbons. The structure is amenable to substitution on the A, M or phosphorus sites and a wide range of isostructural materials can be formed. The occupancy of the type I and II sites can also be varied from four to zero. For example, the compound Na<sub>3</sub>Zr<sub>2</sub>Si<sub>2</sub>PO<sub>12</sub>, Nasicon, has sodium ions in both type I and II sites and has attracted considerable interest because of its high sodium-ion mobility [1,2].

The white compound of composition  $NbTiP_3O_{12}$  with vacant type I and II sites also adopts the Nasicontype structure and has been shown to be capable of direct reaction with several electropositive metals to give blue-black solids in which the metallic species are incorporated within the vacant sites [5]. We have shown [6,7] that the reaction of NbTiP<sub>3</sub>O<sub>12</sub> with elemental tin to give compounds of the type  $Sn_xNbTiP_3O_{12}$  ( $0 < x \le 0.50$ ) involves the incorporation of  $Sn^{2+}$  within the octahedral type I sites of the NbTiP<sub>3</sub>O<sub>12</sub> structure. The charge balance mechanism, which results from the incorporation of  $Sn^{2+}$ ions within the structure has, on the basis of limited Ti K-edge XANES data [7], been associated with the reduction of Nb<sup>5+</sup> as opposed to Ti<sup>4+</sup>. However, since no systematic study of the maintenance of electrical neutrality has been described, we report here on our examination of charge balance in these materials by X-ray photoelectron spectroscopy (XPS).

## **EXPERIMENTAL**

The compound NbTiP<sub>3</sub>O<sub>12</sub> was prepared by the sequential heating of a stoichiometric mixture of niobium(V) oxide, titanium(IV) oxide (anatase) and ammonium dihydrogen phosphate in air at 200 (12 h), 600 (6 h), 900 (15 h), 1000 (5 h) and finally at 1300°C (1 h). Tin was incorporated into NbTiP<sub>3</sub>O<sub>12</sub> to give materials of composition  $Sn_xNbTiP_3O_{12}$ 

<sup>\*</sup> Authors to whom correspondence should be addressed.



Fig. 1. Ti 2p X-ray photoelectron spectra recorded from the compounds  $Sn_xNbTiP_3O_{12}$  ( $0 \le x \le 0.50$ )

 $(0 < x \le 0.50)$  by heating NbTiP<sub>3</sub>O<sub>12</sub> with the powdered elemental metal at 900°C (24 h) in evacuated sealed quartz tubes.

XPS data were recorded with a triple channeltron CLAM2 analyser under an operating vacuum better than  $1.10^{-8}$  torr using Al-K $\alpha$  radiation and a constant analyzer transmission energy of 20 eV. The powdered samples were supported on double-sided adhesive conductive carbon tape. All the spectra were recorded at take-off angles of 90°. All binding energies were charge-corrected to the C 1s signal which was set at 284.6 eV. Sample charging was checked by recording C 1s spectra both before and after the accumulation of each Ti 2p and Nb 3d spectrum and was found to be less than 0.1 eV. All the spectra were computer-fitted using a program based on procedures described in the literature [8]. The binding energies are accurate to  $\pm 0.2$  eV.

## **RESULTS AND DISCUSSION**

The Ti 2p spectra recorded from the compounds  $Sn_xNbTiP_3O_{12}$  ( $0 \le x \le 0.50$ ) are shown in Fig. 1. The binding energies and the relative intensities obtained from the fit of the data are collected in Table 1. The Ti 2p spectrum recorded from white NbTiP<sub>3</sub>O<sub>12</sub> showed only a spin-orbit doublet. The binding energy of the Ti  $2p_{3/2}$  level of 459.5 eV is ~ 0.5–0.7 eV larger than that reported for TiO<sub>2</sub> and  $\sim 1$  eV larger than that observed for Ti<sup>4+</sup> in compounds such as CaTiO<sub>3</sub> or SrTiO<sub>3</sub> [9]. The result indicates that the  $Ti^{4+}$ —O bonds in NbTiP<sub>3</sub>O<sub>12</sub> are more ionic in character than in other compounds in which Ti<sup>4+</sup> is coordinated by oxygen and we associate this with the polarization of the  $Ti^{4+}$ —O bonds by the inductive effect of the P—O bonds [10]. The Ti 2p spectra recorded from the blueblack compounds  $Sn_xNbTiP_3O_{12}$  (0.25  $\leq x \leq 0.50$ ) were characterized by broader lines than those recorded from NbTiP<sub>3</sub>O<sub>12</sub>. The peaks were deconvoluted into two contributions (Fig. 1, Table 1). One of the contributions is similar to that observed in the spectrum recorded from NbTiP<sub>3</sub>O<sub>12</sub>, the second appeared at lower binding energy (Ti  $2p_{3/2} = 457.7$  eV) and we

Table 1. Ti  $2p_{3/2}$  binding energies in the compounds Sn<sub>x</sub>NbTiP<sub>3</sub>O<sub>12</sub> ( $0 \le x \le 0.50$ )

Compound	BE (eV)	$I_{\rm rel}$ (%)	Assignment
NbTiP <sub>3</sub> O <sub>12</sub>	459.5	100	Ti <sup>4+</sup>
Sn <sub>0.25</sub> NbTiP <sub>3</sub> O <sub>12</sub>	459.5	60	Ti <sup>4+</sup>
	457.8	40	Ti <sup>3+</sup>
Sn <sub>0.33</sub> NbTiP <sub>3</sub> O <sub>12</sub>	459.5	48	Ti <sup>4+</sup>
	457.8	52	Ti <sup>3+</sup>
Sn <sub>0.50</sub> NbTiP <sub>3</sub> O <sub>12</sub>	459.3	22	Ti <sup>4+</sup>
	457.7	78	Ti <sup>3+</sup>

Table 2. Nb  $3d_{5/2}$  binding energies in the compounds Sn<sub>x</sub>NbTiP<sub>3</sub>O<sub>12</sub> ( $0 \le x \le 0.50$ )

Compound	BE (eV)	I <sub>rel</sub> (%)	Assignment
NbTiP <sub>3</sub> O <sub>12</sub>	208.2	100	Nb <sup>5+</sup>
Sn <sub>0.25</sub> NbTiP <sub>3</sub> O <sub>12</sub>	208.1	84	Nb <sup>5+</sup>
	206.7	16	Nb <sup>4+</sup>
$\mathbf{Sn}_{0.33}\mathbf{NbTiP_{3}O_{12}}$	208.1	77	Nb <sup>5+</sup>
	207.0	23	$Nb^{4+}$
$Sn_{0.50}NbTiP_3O_{12}$	208.0	80	Nb <sup>s</sup>
	206.7	20	$Nb^{4+}$

associate this with titanium in a lower oxidation state, probably  $Ti^{3+}$  (the Ti  $2p_{3/2}$  binding energy of titanium in  $Ti_2O_3$  is 457.2 eV [11]). The results suggest that the incorporation of tin into the NbTiP<sub>3</sub>O<sub>12</sub> structure results in some reduction of  $Ti^{4+}$  to  $Ti^{3+}$ . The results, Table 1, also indicate that the extent of  $Ti^{4+}$  to  $Ti^{3+}$ reduction increases when larger concentrations of tin are incorporated within the structure.

The Nb 3d spectra recorded from the compounds  $Sn_xNbTiP_3O_{12}$  ( $0 \le x \le 0.50$ ) are shown in Fig. 2. The binding energies and the relative intensities obtained from the fit of the data are collected in Table 2. The Nb 3d spectrum recorded from NbTiP<sub>3</sub>O<sub>12</sub> showed only a spin-orbit doublet. The binding energy of the Nb  $3d_{5/2}$  level, 208.2 eV, is ~ 0.8–1.0 eV higher than that observed for Nb<sub>2</sub>O<sub>5</sub> [12] and is similar to that of Nb<sup>5+</sup> in ionic compounds such as NbCl<sub>5</sub> [12]. We therefore associate this binding energy with a highly ionic Nb<sup>5+</sup> species. The Nb 3d spectra recorded from the compounds  $Sn_xNbTiP_3O_{12}$  (0.25  $\leq x \leq 0.50$ ) were broader than that recorded from NbTiP<sub>3</sub>O<sub>12</sub> and were deconvoluted into two different contributions (Fig. 2, Table 2). One contribution was similar to that observed in the spectrum recorded from NbTiP<sub>3</sub>O<sub>12</sub> and the second appeared at a lower binding energy (Nb  $3d_{5/2} = 206.7 \text{ eV}$ ). We associate this second contribution with Nb<sup>4+</sup> species resulting from the partial reduction of Nb<sup>5+</sup> ions in NbTiP<sub>3</sub>O<sub>12</sub> after the incorporation of tin into the structure as  $Sn^{2+}$ . The results show that the extent of  $Nb^{5+}$  to  $Nb^{4+}$  reduction is less than that of Ti<sup>4+</sup> to Ti<sup>3+</sup> which implies that the reduction of Ti<sup>4+</sup> ions is more easily achieved in these materials than the reduction of Nb<sup>5+</sup>. It is interesting to note that the sum of the relative intensities given in Tables 1 and 2 for the Ti<sup>3+</sup> and Nb<sup>4+</sup> species fit reasonably well with values necessary to achieve electrical neutrality in these materials. For example, since the reactant metallic tin donates two electrons which reduce either Ti<sup>4+</sup> or Nb<sup>5+</sup> in the NbTiP<sub>3</sub>O<sub>12</sub> structure, the compound  $Sn_{0.25}NbTiP_3O_{12}$  may be formulated as  $\operatorname{Sn}_{0.25}(\operatorname{Nb}^{5+})_{1-\nu}(\operatorname{Nb}^{4+})_{\nu}(\operatorname{Ti}^{4+})_{1-\nu}(\operatorname{Ti}^{3+})_{\nu}P_{3}O_{12}$ , and the experimentally determined value of y + z = 0.56agrees well with the expected value of 0.50. Simi-



Intensity (a.u.)

Fig. 2. Nb 3d X-ray photoelectron spectra recorded from the compounds  $Sn_xNbTiP_3O_{12}$  ( $0 \le x \le 0.50$ )

larly, for the compounds  $Sn_{0.33}NbTiP_3O_{12}$  and  $Sn_{0.5}NbTiP_3O_{12}$ , where y+z would be expected to be 0.66 and 1, respectively, the experimentally determined values of 0.75 and 0.98 correlate remarkably well.

In a previous paper [7] we reported, on the basis of Mössbauer spectroscopy and X-ray powder diffraction data, that the upper limit of tin which can be accommodated within the channels of the NbTiP<sub>3</sub>O<sub>12</sub> structure is achieved at ca x = 0.5. On the basis of limited Ti K-edge XANES data [7], it was assumed that Ti<sup>4+</sup> was not reduced on incorporation of tin as a  $Sn^{2+}$  ion and that the material of composition Sn<sub>0.5</sub>NbTiP<sub>3</sub>O<sub>12</sub> corresponded to the situation where all the Nb<sup>5+</sup> is reduced to the tetravalent form. The present work demonstrates a clear reduction of Ti<sup>4+</sup> to Ti<sup>3+</sup> as well as of Nb<sup>5+</sup> to Nb<sup>4+</sup> and endorses earlier magnetic susceptibility measurements [13] which showed Sn<sub>0.5</sub>NbTiP<sub>3</sub>O<sub>12</sub> to be paramagnetic at temperatures down to 4.2 K with the effective magnetic moment being consistent with the presence of Ti<sup>3+</sup> and/or Nb<sup>4+</sup>. We have also recorded the XPS data (Ti 2p and Nb 3d spectra) from  $Sn_{0.66}NbTiP_{3}O_{12}$  and  $Sn_{1.00}NbTiP_3O_{12}$  (which were shown by X-ray powder diffraction and <sup>119</sup>Sn Mössbauer spectroscopy to contain unreacted metallic tin [14]) and they are similar to those recorded from Sn<sub>0.5</sub>NbTiP<sub>3</sub>O<sub>12</sub>. It therefore seems that it is not possible to reduce more than 75-80% of Ti<sup>4+</sup> to the trivalent form or more than 20-25% of Nb<sup>5+</sup> to the tetravalent form upon incorporation of tin, possibly because of the complex electrostatic interactions which can arise within the structure as a result of the existence of a large number of cations in different oxidation states.

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